

FEATURES

- Rail-to-Rail Input and Output
- $90\mu\text{V}$ $V_{OS(MAX)}$ for $V_{CM} = V^-$ to V^+
- High Common Mode Rejection Ratio: 97dB Min
- C-Load™ Stable Version (LT1219)
- High A_{VOL} : 500V/mV Minimum Driving 10k Ω Load
- Wide Supply Range:
 - 2V to $\pm 15\text{V}$ (LT1218/LT1219)
 - 2V to $\pm 5\text{V}$ (LT1218L/LT1219L)
- Shutdown Mode: $I_S < 30\mu\text{A}$
- Low Supply Current: 420 μA Max
- Low Input Bias Current: 18nA Typical
- 300kHz Gain-Bandwidth Product (LT1218)
- Slew Rate: 0.10V/ μs (LT1218)

APPLICATIONS

- Driving A/D Converters
- Test Equipment Amplifiers
- MUX Amplifiers

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DESCRIPTION

The LT[®]1218/LT1219 are bipolar op amps which combine rail-to-rail input and output operation with precision specifications. Unlike other rail-to-rail amplifiers, the LT1218/LT1219's input offset voltage is a low $90\mu\text{V}$ across the entire rail-to-rail input range, not just a portion of it. Using a patented technique, both input stages of the LT1218/LT1219 are trimmed: one at the negative supply and the other at the positive supply. The resulting common mode rejection of 97dB minimum is much better than other rail-to-rail input op amps. A minimum open-loop gain of 500V/mV into a 10k load virtually eliminates all gain error.

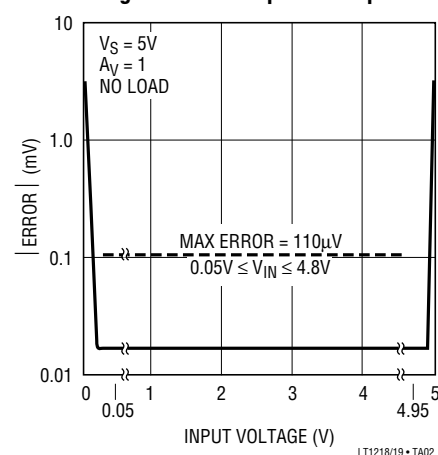
The LT1218 has conventional compensation which assures stability for capacitive loads of 1000pF or less. The LT1219 has compensation that requires the use of a 0.1 μF output capacitor, which improves the amplifier's supply rejection and reduces output impedance at high frequencies. The output capacitor's filtering action also reduces high frequency noise, which is beneficial when driving A/D converters.

High and low voltage versions of the devices are offered. Operation is specified for 3V, 5V and $\pm 5\text{V}$ supplies for the LT1218L/LT1219L and 3V, 5V and $\pm 15\text{V}$ for the LT1218/LT1219.

TYPICAL APPLICATION



Voltage Follower Input to Output Error

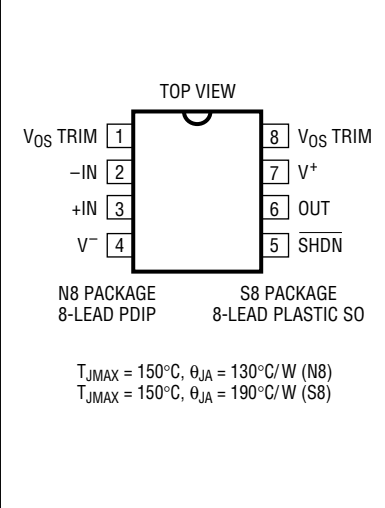


LT1218/LT1219

ABSOLUTE MAXIMUM RATINGS

| | |
|--|----------------|
| Supply Voltage | |
| LT1218/LT1219 | ±18V |
| LT1218L/LT1219L | ±8V |
| Input Current | ±15mA |
| Output Short-Circuit Duration (Note 1) | Continuous |
| Operating Temperature Range | -40°C to 85°C |
| Specified Temperature Range (Note 3) ... | -40°C to 85°C |
| Storage Temperature Range | -65°C to 150°C |
| Junction Temperature | 150°C |
| Lead Temperature (Soldering, 10 sec) | 300°C |

PACKAGE/ORDER INFORMATION

| | |
|--|--|
|  | ORDER PART NUMBER |
| | LT1218CN8 LT1218CS8 LT1218LCN8 LT1218LCS8 LT1219CN8 LT1219CS8 LT1219LCN8 LT1219LCS8 |
| | S8 PART MARKING |
| | 1218 1219 1218L 1219L |

Consult factory for Industrial and Military grades.

ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$, $V_S = 5\text{V}$, 0V ; $V_S = 3\text{V}$, 0V ; $V_{CM} = V_O = \text{half supply}$, $V_{SHDN} = V^+$, unless otherwise noted.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-----------------|-------------------------------|--|---|---|-----------------|--|
| V_{OS} | Input Offset Voltage | $V_{CM} = V^+$ $V_{CM} = V^-$ | | 25 25 | 90 90 | μV μV |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{CM} = V^-$ to V^+ | | 15 | 70 | μV |
| I_B | Input Bias Current | $V_{CM} = V^+$ $V_{CM} = V^-$ | -70 | 30 -18 | 70 | nA nA |
| ΔI_B | Input Bias Current Shift | $V_{CM} = V^-$ to V^+ | | 50 | 140 | nA |
| I_{OS} | Input Offset Current | $V_{CM} = V^+$ $V_{CM} = V^-$ | | 5 2 | 18 18 | nA nA |
| ΔI_{OS} | Input Offset Current Shift | $V_{CM} = V^-$ to V^+ | | 5 | 18 | nA |
| e_n | Input Noise Voltage Density | $f = 1\text{kHz}$ | | 33 | | $\text{nV}/\sqrt{\text{Hz}}$ |
| i_n | Input Noise Current Density | $f = 1\text{kHz}$ | | 0.09 | | $\text{pA}/\sqrt{\text{Hz}}$ |
| A_{VOL} | Large-Signal Voltage Gain | $V_S = 5\text{V}$, $V_O = 50\text{mV}$ to 4.8V , $R_L = 10\text{k}$ $V_S = 3\text{V}$, $V_O = 50\text{mV}$ to 2.8V , $R_L = 10\text{k}$ | 250 200 | 1000 750 | | V/mV V/mV |
| CMRR | Common Mode Rejection Ratio | $V_S = 5\text{V}$, $V_{CM} = V^-$ to V^+ $V_S = 3\text{V}$, $V_{CM} = V^-$ to V^+ | 97 92 | 110 106 | | dB dB |
| PSRR | Power Supply Rejection Ratio | $V_S = 2.3\text{V}$ to 12V , $V_{CM} = 0\text{V}$, $V_O = 0.5\text{V}$ | 90 | 100 | | dB |
| V_{OL} | Output Voltage Swing LOW | No Load $I_{SINK} = 0.5\text{mA}$ $I_{SINK} = 2.5\text{mA}$ | | 4 45 120 | 12 90 240 | mV mV mV |
| V_{OH} | Output Voltage Swing HIGH | No Load $I_{SOURCE} = 0.5\text{mA}$ $I_{SOURCE} = 2.5\text{mA}$ | $V^+ - 0.012$ $V^+ - 0.130$ $V^+ - 0.400$ | $V^+ - 0.003$ $V^+ - 0.065$ $V^+ - 0.210$ | | V V V |
| I_{SC} | Short-Circuit Current | $V_S = 5\text{V}$ $V_S = 3\text{V}$ | 5 4 | 10 7 | | mA mA |
| I_S | Supply Current | $V_S = 5\text{V}$ $V_S = 3\text{V}$ | | 370 370 | 420 410 | μA μA |
| | Positive Supply Current, SHDN | $V_S = 5\text{V}$, $V_{SHDN} = 0\text{V}$ $V_S = 3\text{V}$, $V_{SHDN} = 0\text{V}$ | | 9 6 | 30 20 | μA μA |

ELECTRICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$, $V_S = 5\text{V}$, 0V ; $V_S = 3\text{V}$, 0V ; $V_{CM} = V_0 = \text{half supply}$, $V_{\overline{\text{SHDN}}} = V^+$, unless otherwise noted.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|--------|--|--------------|-----|------|-----|------------------|
| SR | Slew Rate (LT1218/LT1218L) (LT1219/LT1219L) | $A_V = -1$ | | 0.10 | | V/ μs |
| | | $A_V = -1$ | | 0.05 | | V/ μs |
| GBW | Gain Bandwidth Product (LT1218/LT1218L) (LT1219/LT1219L) | $A_V = 1000$ | | 0.30 | | MHz |
| | | $A_V = 1000$ | | 0.15 | | MHz |

$0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$, $V_S = 5\text{V}$, 0V ; $V_S = 3\text{V}$, 0V ; $V_{CM} = V_0 = \text{half supply}$, $V_{\overline{\text{SHDN}}} = V^+$, unless otherwise noted.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-----------------|-------------------------------|--|-----|---------------|---------------|------------------------------|
| V_{OS} | Input Offset Voltage | $V_{CM} = V^+$ | ● | 75 | 200 | μV |
| | | $V_{CM} = V^-$ | ● | 75 | 200 | μV |
| $V_{OS\ TC}$ | Input Offset Drift | (Note 2) | ● | 1 | 3 | $\mu\text{V}/^\circ\text{C}$ |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{CM} = V^- \text{ to } V^+$ | ● | 25 | 80 | μV |
| I_B | Input Bias Current | $V_{CM} = V^+$ | ● | 30 | 75 | nA |
| | | $V_{CM} = V^-$ | ● | -75 | -18 | nA |
| ΔI_B | Input Bias Current Shift | $V_{CM} = V^- \text{ to } V^+$ | ● | 50 | 150 | nA |
| I_{OS} | Input Offset Current | $V_{CM} = V^+$ | ● | 5 | 25 | nA |
| | | $V_{CM} = V^-$ | ● | 3 | 25 | nA |
| ΔI_{OS} | Input Offset Current Shift | $V_{CM} = V^- \text{ to } V^+$ | ● | 5 | 25 | nA |
| A_{VOL} | Large-Signal Voltage Gain | $V_S = 5\text{V}$, $V_0 = 50\text{mV}$ to 4.8V , $R_L = 10\text{k}$ | ● | 250 | 1000 | V/mV |
| | | $V_S = 3\text{V}$, $V_0 = 50\text{mV}$ to 2.8V , $R_L = 10\text{k}$ | ● | 150 | 750 | V/mV |
| CMRR | Common Mode Rejection Ratio | $V_S = 5\text{V}$, $V_{CM} = V^- \text{ to } V^+$ | ● | 96 | 104 | dB |
| | | $V_S = 3\text{V}$, $V_{CM} = V^- \text{ to } V^+$ | ● | 91 | 106 | dB |
| PSRR | Power Supply Rejection Ratio | $V_S = 2.3\text{V}$ to 12V , $V_{CM} = 0\text{V}$, $V_0 = 0.5\text{V}$ | ● | 88 | 100 | dB |
| V_{OL} | Output Voltage Swing LOW | No Load | ● | 4 | 14 | mV |
| | | $I_{\text{SINK}} = 0.5\text{mA}$ | ● | 45 | 100 | mV |
| | | $I_{\text{SINK}} = 2.5\text{mA}$ | ● | 130 | 290 | mV |
| V_{OH} | Output Voltage Swing HIGH | No Load | ● | $V^+ - 0.014$ | $V^+ - 0.004$ | V |
| | | $I_{\text{SOURCE}} = 0.5\text{mA}$ | ● | $V^+ - 0.150$ | $V^+ - 0.075$ | V |
| | | $I_{\text{SOURCE}} = 2.5\text{mA}$ | ● | $V^+ - 0.480$ | $V^+ - 0.240$ | V |
| I_{SC} | Short-Circuit Current | $V_S = 5\text{V}$ | ● | 4 | 7 | mA |
| | | $V_S = 3\text{V}$ | ● | 3 | 6 | mA |
| I_S | Supply Current | $V_S = 5\text{V}$ | ● | 370 | 485 | μA |
| | | $V_S = 3\text{V}$ | ● | 370 | 475 | μA |
| | Positive Supply Current, SHDN | $V_S = 5\text{V}$, $V_{\overline{\text{SHDN}}} = 0\text{V}$ | ● | 9 | 36 | μA |
| | | $V_S = 3\text{V}$, $V_{\overline{\text{SHDN}}} = 0\text{V}$ | ● | 6 | 26 | μA |

$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$, $V_S = 5\text{V}$, 0V ; $V_S = 3\text{V}$, 0V ; $V_{CM} = V_0 = \text{half supply}$, $V_{\overline{\text{SHDN}}} = V^+$, unless otherwise noted. (Note 3)

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-----------------|----------------------------|--|-----|-----|-----|------------------------------|
| V_{OS} | Input Offset Voltage | $V_{CM} = V^+ - 0.15$ | ● | | 400 | μV |
| | | $V_{CM} = V^- + 0.15$ | ● | | 400 | μV |
| $V_{OS\ TC}$ | Input Offset Drift | (Note 2) | ● | 1 | 4 | $\mu\text{V}/^\circ\text{C}$ |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{CM} = V^+ - 0.15 \text{ to } V^- + 0.15$ | ● | 30 | 105 | μV |
| I_B | Input Bias Current | $V_{CM} = V^+ - 0.15$ | ● | | 80 | nA |
| | | $V_{CM} = V^- + 0.15$ | ● | -80 | | nA |
| ΔI_B | Input Bias Current Shift | $V_{CM} = V^+ - 0.15 \text{ to } V^- + 0.15$ | ● | | 160 | nA |
| I_{OS} | Input Offset Current | $V_{CM} = V^+ - 0.15$ | ● | | 40 | nA |
| | | $V_{CM} = V^- + 0.15$ | ● | | 40 | nA |
| ΔI_{OS} | Input Offset Current Shift | $V_{CM} = V^+ - 0.15 \text{ to } V^- + 0.15$ | ● | | 40 | nA |

ELECTRICAL CHARACTERISTICS

-40°C ≤ T_A ≤ 85°C, V_S = 5V, 0V; V_S = 3V, 0V; V_{CM} = V_O = half supply, V_{SHDN} = V⁺, unless otherwise noted. (Note 3)

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS | |
|------------------|-------------------------------|---|-----|------------------------|------------------------|-------|----|
| A _{VOL} | Large-Signal Voltage Gain | V _S = 5V, V _O = 50mV to 4.8V, R _L = 10k | ● | 150 | 500 | V/mV | |
| | | V _S = 3V, V _O = 50mV to 2.8V, R _L = 10k | ● | 100 | 500 | V/mV | |
| CMRR | Common Mode Rejection Ratio | V _S = 5V, V _{CM} = V ⁺ - 0.15 to V ⁻ + 0.15 | ● | 93 | 102 | dB | |
| | | V _S = 3V, V _{CM} = V ⁺ - 0.15 to V ⁻ + 0.15 | ● | 88 | 100 | dB | |
| PSRR | Power Supply Rejection Ratio | V _S = 2.3V to 12V, V _{CM} = 0V, V _O = 0.5V | ● | 86 | 100 | dB | |
| V _{OL} | Output Voltage Swing LOW | No Load | ● | | 5 | 15 | mV |
| | | I _{SINK} = 0.5mA | ● | | 50 | 105 | mV |
| | | I _{SINK} = 2.5mA | ● | | 130 | 300 | mV |
| V _{OH} | Output Voltage Swing HIGH | No Load | ● | V ⁺ - 0.015 | V ⁺ - 0.004 | | mV |
| | | I _{SOURCE} = 0.5mA | ● | V ⁺ - 0.160 | V ⁺ - 0.070 | | mV |
| | | I _{SOURCE} = 2.5mA | ● | V ⁺ - 0.500 | V ⁺ - 0.250 | | mV |
| I _{SC} | Short-Circuit Current | V _S = 5V | ● | 4 | 7 | mA | |
| | | V _S = 3V | ● | 3 | 7 | mA | |
| I _S | Supply Current | V _S = 5V | ● | | 410 | 505 | μA |
| | | V _S = 3V | ● | | 400 | 495 | μA |
| | Positive Supply Current, SHDN | V _S = 5V, V _{SHDN} = 0V | ● | | 15 | 50 | μA |
| | | V _S = 3V, V _{SHDN} = 0V | ● | | 13 | 40 | μA |

LT1218L/LT1219L only; T_A = 25°C, V_S = ±5V, V_{CM} = 0V, V_O = 0V, V_{SHDN} = 5V, unless otherwise noted.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|------------------|--|--|------------------------|------------------------|------------------------|-------|
| V _{OS} | Input Offset Voltage | V _{CM} = V ⁺ | | 35 | 140 | μV |
| | | V _{CM} = V ⁻ | | 35 | 140 | μV |
| ΔV _{OS} | Input Offset Voltage Shift | V _{CM} = V ⁻ to V ⁺ | | 20 | 70 | μV |
| I _B | Input Bias Current | V _{CM} = V ⁺ | | 30 | 70 | nA |
| | | V _{CM} = V ⁻ | -70 | -18 | | nA |
| ΔI _B | Input Bias Current Shift | V _{CM} = V ⁻ to V ⁺ | | 50 | 140 | nA |
| I _{OS} | Input Offset Current | V _{CM} = V ⁺ | | 5 | 18 | nA |
| | | V _{CM} = V ⁻ | | 2 | 18 | nA |
| ΔI _{OS} | Input Offset Current Shift | V _{CM} = V ⁻ to V ⁺ | | 5 | 18 | nA |
| A _{VOL} | Large-Signal Voltage Gain | V _O = -4.7V to 4.7V, R _L = 10k | | 500 | 2800 | V/mV |
| | | V _O = -4.5V to 4.5V, R _L = 2k | | 300 | 1300 | V/mV |
| CMRR | Common Mode Rejection Ratio | V _{CM} = V ⁻ to V ⁺ | 103 | 114 | | dB |
| V _{OL} | Output Voltage Swing LOW | No Load | | V ⁻ + 0.004 | V ⁻ + 0.012 | V |
| | | I _{SINK} = 0.5mA | | V ⁻ + 0.045 | V ⁻ + 0.090 | V |
| | | I _{SINK} = 5mA | | V ⁻ + 0.180 | V ⁻ + 0.525 | V |
| V _{OH} | Output Voltage Swing HIGH | No Load | V ⁺ - 0.012 | V ⁺ - 0.003 | | V |
| | | I _{SOURCE} = 0.5mA | V ⁺ - 0.130 | V ⁺ - 0.065 | | V |
| | | I _{SOURCE} = 5mA | V ⁺ - 0.800 | V ⁺ - 0.350 | | V |
| I _{SC} | Short-Circuit Current | | 6 | 12 | mA | |
| I _S | Supply Current | | | 400 | 430 | μA |
| | | Positive Supply Current, SHDN | V _{SHDN} = 0V | | 10 | 40 |
| SR | Slew Rate (LT1218/LT1218L) (LT1219/LT1219L) | A _V = -1, R _L = Open, V _O = ±3.5V | 0.06 | 0.10 | | V/μs |
| | | A _V = -1, R _L = Open, V _O = ±3.5V | 0.03 | 0.05 | | V/μs |
| GBW | Gain-Bandwidth Product (LT1218/LT1218L) (LT1219/LT1219L) | A _V = 1000 | 0.2 | 0.30 | | MHz |
| | | A _V = 1000 | 0.1 | 0.15 | | MHz |

ELECTRICAL CHARACTERISTICS

LT1218L/LT1219L only; $0^{\circ}\text{C} \leq T_A \leq 70^{\circ}\text{C}$, $V_S = \pm 5\text{V}$, $V_{CM} = 0\text{V}$, $V_O = 0\text{V}$, $V_{\overline{\text{SHDN}}} = 5\text{V}$, unless otherwise noted.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-----------------|-------------------------------|--|-----|---------------|---------------|---------------|
| V_{OS} | Input Offset Voltage | $V_{CM} = V^+$ | ● | 100 | 250 | μV |
| | | $V_{CM} = V^-$ | ● | 100 | 250 | μV |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{CM} = V^-$ to V^+ | ● | 30 | 90 | μV |
| I_B | Input Bias Current | $V_{CM} = V^+$ | ● | 30 | 75 | nA |
| | | $V_{CM} = V^-$ | ● | -75 | -18 | nA |
| ΔI_B | Input Bias Current | $V_{CM} = V^-$ to V^+ | ● | 50 | 150 | nA |
| I_{OS} | Input Offset Current | $V_{CM} = V^+$ | ● | 5 | 25 | nA |
| | | $V_{CM} = V^-$ | ● | 3 | 25 | nA |
| ΔI_{OS} | Input Offset Current Shift | $V_{CM} = V^-$ to V^+ | ● | 5 | 20 | nA |
| A_{VOL} | Large-Signal Voltage Gain | $V_O = -4.7\text{V}$ to 4.7V , $R_L = 10\text{k}$ | ● | 375 | 2800 | V/mV |
| | | $V_O = -4.5\text{V}$ to 4.5V , $R_L = 2\text{k}$ | ● | 275 | 1300 | V/mV |
| CMRR | Common Mode Rejection Ratio | $V_{CM} = V^-$ to V^+ | ● | 100 | 110 | dB |
| V_{OL} | Output Voltage Swing LOW | No Load | ● | $V^- + 0.004$ | $V^- + 0.014$ | V |
| | | $I_{\text{SINK}} = 0.5\text{mA}$ | ● | $V^- + 0.045$ | $V^- + 0.100$ | V |
| | | $I_{\text{SINK}} = 5\text{mA}$ | ● | $V^- + 0.200$ | $V^- + 0.580$ | V |
| V_{OH} | Output Voltage Swing HIGH | No Load | ● | $V^+ - 0.014$ | $V^+ - 0.004$ | V |
| | | $I_{\text{SOURCE}} = 0.5\text{mA}$ | ● | $V^+ - 0.150$ | $V^+ - 0.075$ | V |
| | | $I_{\text{SOURCE}} = 5\text{mA}$ | ● | $V^+ - 0.920$ | $V^+ - 0.450$ | V |
| I_{SC} | Short-Circuit Current | | ● | 5 | 10 | mA |
| I_S | Supply Current | | ● | 400 | 495 | μA |
| | Positive Supply Current, SHDN | $V_{\overline{\text{SHDN}}} = 0\text{V}$ | ● | 11 | 54 | μA |

LT1218L, LT1219L only; $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, $V_S = \pm 5\text{V}$; $V_{CM} = 0\text{V}$, $V_O = 0\text{V}$, $V_{\overline{\text{SHDN}}} = 5\text{V}$, unless otherwise noted. (Note 3)

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-----------------|-------------------------------|--|-----|---------------|---------------|---------------|
| V_{OS} | Input Offset Voltage | $V_{CM} = V^+ - 0.15$ | ● | 125 | 500 | μV |
| | | $V_{CM} = V^- + 0.15$ | ● | 125 | 500 | μV |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{CM} = V^+ - 0.15$ to $V^- + 0.15$ | ● | 35 | 120 | μV |
| I_B | Input Bias Current | $V_{CM} = V^+ - 0.15$ | ● | | 80 | nA |
| | | $V_{CM} = V^- + 0.15$ | ● | -80 | | nA |
| ΔI_B | Input Bias Current | $V_{CM} = V^+ - 0.15$ to $V^- + 0.15$ | ● | | 160 | nA |
| I_{OS} | Input Offset Current Shift | $V_{CM} = V^+ - 0.15$ | ● | | 40 | nA |
| | | $V_{CM} = V^- + 0.15$ | ● | | 40 | nA |
| ΔI_{OS} | Input Offset Current Shift | $V_{CM} = V^+ - 0.15$ to $V^- + 0.15$ | ● | | 40 | nA |
| A_{VOL} | Large-Signal Voltage Gain | $V_O = -4.7\text{V}$ to 4.7V , $R_L = 10\text{k}$ | ● | 300 | 2000 | V/mV |
| | | $V_O = -4.5\text{V}$ to 4.5V , $R_L = 2\text{k}$ | ● | 200 | 600 | V/mV |
| CMRR | Common Mode Rejection Ratio | $V_{CM} = V^+ - 0.15$ to $V^- + 0.15$ | ● | 98 | 109 | dB |
| V_{OL} | Output Voltage Swing LOW | No Load | ● | $V^- + 0.005$ | $V^- + 0.015$ | V |
| | | $I_{\text{SINK}} = 0.5\text{mA}$ | ● | $V^- + 0.050$ | $V^- + 0.105$ | V |
| | | $I_{\text{SINK}} = 2.5\text{mA}$ | ● | $V^- + 0.200$ | $V^- + 0.620$ | V |
| V_{OH} | Output Voltage Swing HIGH | No Load | ● | $V^+ - 0.015$ | $V^+ - 0.004$ | V |
| | | $I_{\text{SOURCE}} = 0.5\text{mA}$ | ● | $V^+ - 0.160$ | $V^+ - 0.070$ | V |
| | | $I_{\text{SOURCE}} = 2.5\text{mA}$ | ● | $V^+ - 1.000$ | $V^+ - 0.400$ | V |
| I_{SC} | Short-Circuit Current | | ● | 5 | 10 | mA |
| I_S | Supply Current | | ● | 420 | 525 | μA |
| | Positive Supply Current, SHDN | $V_{\overline{\text{SHDN}}} = 0\text{V}$ | ● | 18 | 60 | μA |

ELECTRICAL CHARACTERISTICS

LT1218/LT1219 only; $T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{V}$, $V_{CM} = 0\text{V}$, $V_O = 0\text{V}$, $V_{\overline{\text{SHDN}}} = 15\text{V}$, unless otherwise noted.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-----------------|--|--|---------------|---------------|---------------|------------------|
| V_{OS} | Input Offset Voltage | $V_{CM} = V^+$ | | 85 | 200 | μV |
| | | $V_{CM} = V^-$ | | 85 | 200 | μV |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{CM} = V^-$ to V^+ | | 30 | 70 | μV |
| I_B | Input Bias Current | $V_{CM} = V^+$ | | 30 | 70 | nA |
| | | $V_{CM} = V^-$ | -70 | -18 | | nA |
| ΔI_B | Input Bias Current | $V_{CM} = V^-$ to V^+ | | 50 | 140 | nA |
| I_{OS} | Input Offset Current | $V_{CM} = V^+$ | | 5 | 18 | nA |
| | | $V_{CM} = V^-$ | | 2 | 18 | nA |
| ΔI_{OS} | Input Offset Current Shift | $V_{CM} = V^-$ to V^+ | | 5 | 18 | nA |
| A_{VOL} | Large-Signal Voltage Gain | $V_O = -14.7\text{V}$ to 14.7V , $R_L = 10\text{k}$ | 1000 | 4000 | | V/mV |
| | | $V_O = -10\text{V}$ to 10V , $R_L = 2\text{k}$ | 500 | 2000 | | V/mV |
| CMRR | Common Mode Rejection Ratio | $V_{CM} = V^-$ to V^+ | 113 | 120 | | dB |
| PSRR | Power Supply Rejection Ratio | $V_S = \pm 5\text{V}$ to $\pm 15\text{V}$ | 100 | 110 | | dB |
| V_{OL} | Output Voltage Swing LOW | No Load | | $V^- + 0.004$ | $V^- + 0.012$ | V |
| | | $I_{SINK} = 0.5\text{mA}$ | | $V^- + 0.045$ | $V^- + 0.090$ | V |
| | | $I_{SINK} = 5\text{mA}$ | | $V^- + 0.270$ | $V^- + 0.525$ | V |
| V_{OH} | Output Voltage Swing HIGH | No Load | $V^+ - 0.012$ | $V^+ - 0.003$ | | V |
| | | $I_{SOURCE} = 0.5\text{mA}$ | $V^+ - 0.130$ | $V^+ - 0.065$ | | V |
| | | $I_{SOURCE} = 5\text{mA}$ | $V^+ - 0.800$ | $V^+ - 0.580$ | | V |
| I_{SC} | Short-Circuit Current | | 10 | 20 | | mA |
| I_S | Supply Current | | | 425 | 550 | μA |
| | Positive Supply Current, SHDN | $V_{\overline{\text{SHDN}}} = 0\text{V}$ | | 15 | 40 | μA |
| SR | Slew Rate (LT1218/LT1218L) (LT1219/LT1219L) | $A_V = -1$ | | 0.10 | | V/ μs |
| | | $A_V = -1$ | | 0.05 | | V/ μs |
| GBW | Gain Bandwidth Product (LT1218/LT1218L) (LT1219/LT1219L) | $A_V = 1000$ | | 0.28 | | MHz |
| | | $A_V = 1000$ | | 0.15 | | MHz |

LT1218/LT1219 only; $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$, $V_S = \pm 15\text{V}$, $V_{CM} = 0\text{V}$, $V_O = 0\text{V}$, $V_{\overline{\text{SHDN}}} = 15\text{V}$, unless otherwise noted.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-----------------|------------------------------|--|-----|---------------|---------------|---------------|
| V_{OS} | Input Offset Voltage | $V_{CM} = V^+$ | ● | 120 | 300 | μV |
| | | $V_{CM} = V^-$ | ● | 120 | 300 | μV |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{CM} = V^-$ to V^+ | ● | 50 | 105 | μV |
| I_B | Input Bias Current | $V_{CM} = V^+$ | ● | 30 | 75 | nA |
| | | $V_{CM} = V^-$ | ● | -75 | -18 | nA |
| ΔI_B | Input Bias Current | $V_{CM} = V^-$ to V^+ | ● | 50 | 150 | nA |
| I_{OS} | Input Offset Current | $V_{CM} = V^+$ | ● | 5 | 25 | nA |
| | | $V_{CM} = V^-$ | ● | 3 | 25 | nA |
| ΔI_{OS} | Input Offset Current Shift | $V_{CM} = V^-$ to V^+ | ● | 5 | 20 | nA |
| A_{VOL} | Large-Signal Voltage Gain | $V_O = -14.7\text{V}$ to 14.7V , $R_L = 10\text{k}$ | ● | 750 | 3000 | V/mV |
| | | $V_O = -10\text{V}$ to 10V , $R_L = 2\text{k}$ | ● | 500 | 1500 | V/mV |
| CMRR | Common Mode Rejection Ratio | $V_{CM} = V^-$ to V^+ | ● | 109 | 114 | dB |
| PSRR | Power Supply Rejection Ratio | $V_S = \pm 5\text{V}$ to $\pm 15\text{V}$ | ● | 97 | 110 | dB |
| V_{OL} | Output Voltage Swing LOW | No Load | ● | $V^- + 0.004$ | $V^- + 0.014$ | V |
| | | $I_{SINK} = 0.5\text{mA}$ | ● | $V^- + 0.045$ | $V^- + 0.100$ | V |
| | | $I_{SINK} = 5\text{mA}$ | ● | $V^- + 0.310$ | $V^- + 0.580$ | V |
| V_{OH} | Output Voltage Swing HIGH | No Load | ● | $V^+ - 0.014$ | $V^+ - 0.003$ | V |
| | | $I_{SOURCE} = 0.5\text{mA}$ | ● | $V^+ - 0.150$ | $V^+ - 0.075$ | V |
| | | $I_{SOURCE} = 5\text{mA}$ | ● | $V^+ - 0.920$ | $V^+ - 0.700$ | V |

ELECTRICAL CHARACTERISTICS

LT1218/LT1219 only; $0^{\circ}\text{C} \leq T_A \leq 70^{\circ}\text{C}$, $V_S = \pm 15\text{V}$, $V_{CM} = 0\text{V}$, $V_O = 0\text{V}$, $V_{\overline{\text{SHDN}}} = 15\text{V}$, unless otherwise noted.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|----------|-------------------------------|--|-----|-----|-----|---------------|
| I_{SC} | Short-Circuit Current | | 8 | 17 | | mA |
| I_S | Supply Current | | | 450 | 600 | μA |
| | Positive Supply Current, SHDN | $V_{\overline{\text{SHDN}}} = 0\text{V}$ | | 20 | 54 | μA |

LT1218, LT1219 only; $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$, $V_S = \pm 15\text{V}$; $V_{CM} = 0\text{V} = V_O = 0\text{V}$, $V_{\overline{\text{SHDN}}} = 15\text{V}$, unless otherwise noted. (Note 3)

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
|-----------------|-------------------------------|---|---|---|---|--------------------------------|
| V_{OS} | Input Offset Voltage | $V_{CM} = V^+ - 0.15$ $V_{CM} = V^- + 0.15$ | | 150 | 600 | μV μV |
| ΔV_{OS} | Input Offset Voltage Shift | $V_{CM} = V^+ - 0.15$ to $V^- + 0.15$ | | 50 | 165 | μV |
| I_B | Input Bias Current | $V_{CM} = V^+ - 0.15$ $V_{CM} = V^- + 0.15$ | -80 | | 80 | nA nA |
| ΔI_B | Input Bias Current | $V_{CM} = V^+ - 0.15$ to $V^- + 0.15$ | | | 160 | nA |
| I_{OS} | Input Offset Current | $V_{CM} = V^+ - 0.15$ $V_{CM} = V^- + 0.15$ | | | 40 | nA nA |
| ΔI_{OS} | Input Offset Current Shift | $V_{CM} = V^+ - 0.15$ to $V^- + 0.15$ | | | 40 | nA |
| A_{VOL} | Large-Signal Voltage Gain | $V_O = -14.7\text{V}$ to 14.7V , $R_L = 10\text{k}$ $V_O = -10\text{V}$ to 10V , $R_L = 2\text{k}$ | 500 | 3000 | | V/mV V/mV |
| CMRR | Common Mode Rejection Ratio | $V_{CM} = V^+ - 0.15$ to $V^- + 0.15$ | 105 | 114 | | dB |
| PSRR | Power Supply Rejection Ratio | $V_S = \pm 5\text{V}$ to $\pm 15\text{V}$ | 96 | 110 | | dB |
| V_{OL} | Output Voltage Swing LOW | No Load $I_{SINK} = 0.5\text{mA}$ $I_{SINK} = 2.5\text{mA}$ | | $V^- + 0.005$ $V^- + 0.050$ $V^- + 0.200$ | $V^- + 0.015$ $V^- + 0.105$ $V^- + 0.620$ | V V V |
| V_{OH} | Output Voltage Swing HIGH | No Load $I_{SOURCE} = 0.5\text{mA}$ $I_{SOURCE} = 2.5\text{mA}$ | $V^+ - 0.015$ $V^+ - 0.160$ $V^+ - 1.000$ | $V^+ - 0.004$ $V^+ - 0.070$ $V^+ - 0.400$ | | V V V |
| I_{SC} | Short-Circuit Current | | 5 | 14 | | mA |
| I_S | Supply Current | | | | 650 | μA |
| | Positive Supply Current, SHDN | $V_{\overline{\text{SHDN}}} = 0\text{V}$ | | | 60 | μA |

The ● denotes specifications which apply over the full operating temperature range.

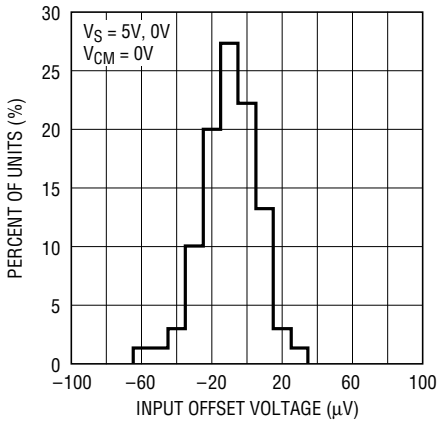
Note 1: A heat sink may be required to keep the junction temperature below the Absolute Maximum Rating when the output is shorted indefinitely.

Note 2: This parameter is not 100% tested.

Note 3: The LT1218/LT1219 are designed, characterized and expected to meet these extended temperature limits, but are not tested at -40°C and 85°C . Guaranteed I grade part are available: consult factory.

TYPICAL PERFORMANCE CHARACTERISTICS

V_{OS} Distribution, $V_{CM} = 0V$



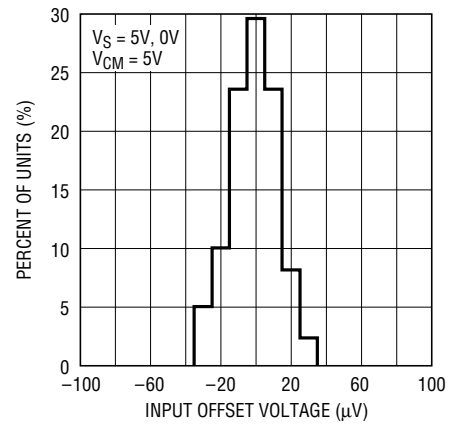
LT1218/19 • TPC01

V_{OS} Shift, $V_{CM} = 0V$ to $5V$



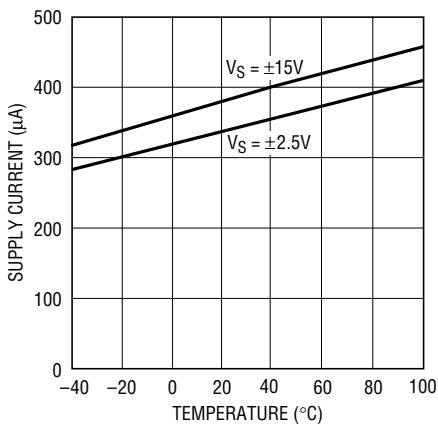
LT1218/19 • TPC02

V_{OS} Distribution, $V_{CM} = 5V$



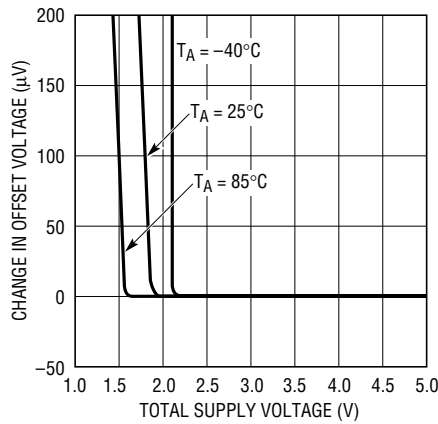
LT1218/19 • TPC03

Supply Current vs Temperature



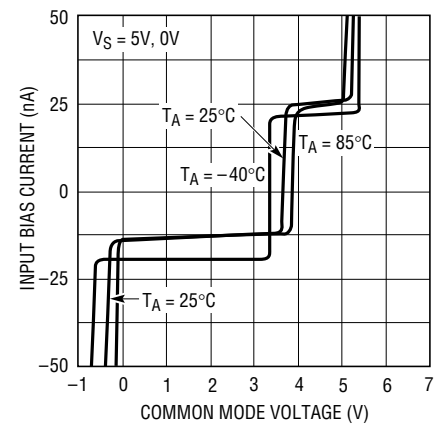
LT1218/19 • TPC04

Minimum Supply Voltage



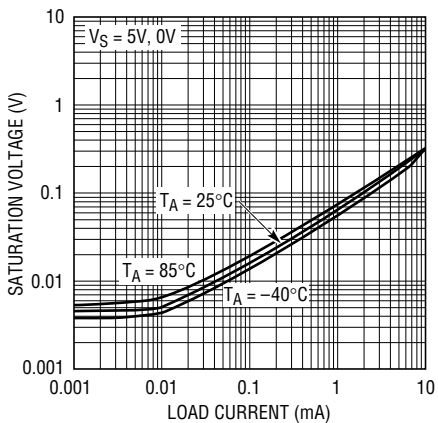
LT1218/19 • TPC05

Input Bias Current vs Common Mode Voltage



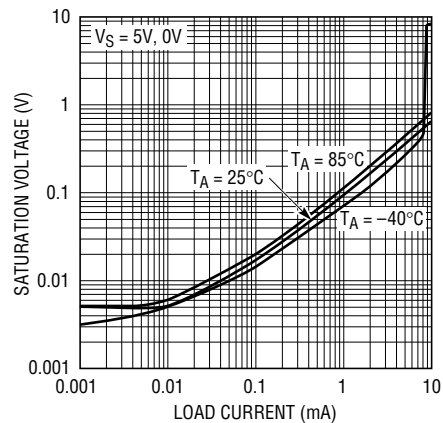
LT1218/19 • TPC06

Output Saturation Voltage vs Load Current (Output Low)



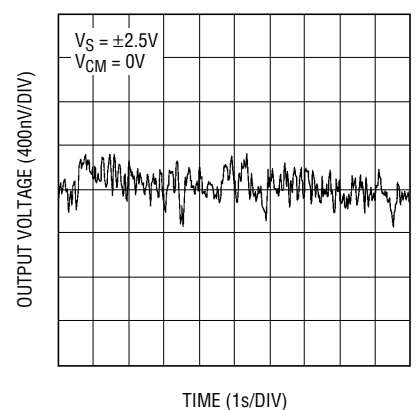
LT1218/19 • TPC07

Output Saturation Voltage vs Load Current (Output High)



LT1218/19 • TPC08

0.1Hz to 10Hz Output Voltage Noise



LT1218/19 • TPC09

TYPICAL PERFORMANCE CHARACTERISTICS

Noise Voltage Spectrum



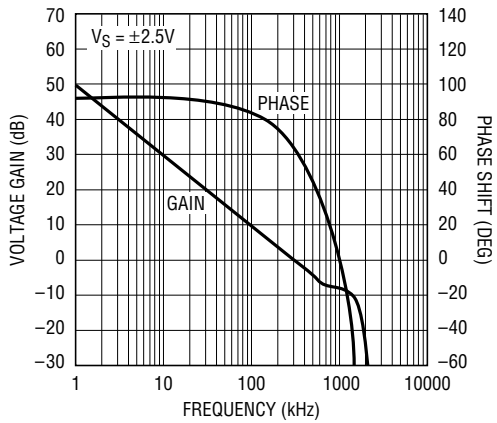
LT1218/19 • TPC10

Noise Current Spectrum



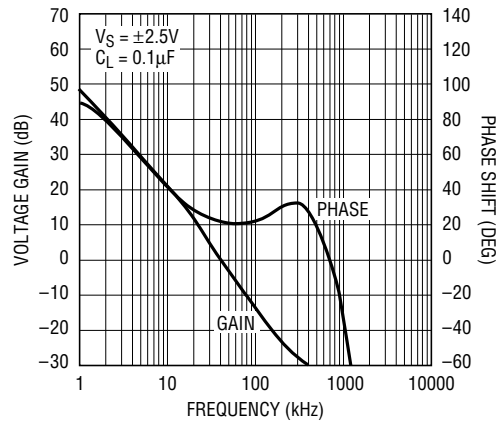
LT1218/19 • TPC11

LT1218 Gain and Phase Shift vs Frequency



LT1218/19 • TPC12

LT1219 Gain and Phase Shift vs Frequency



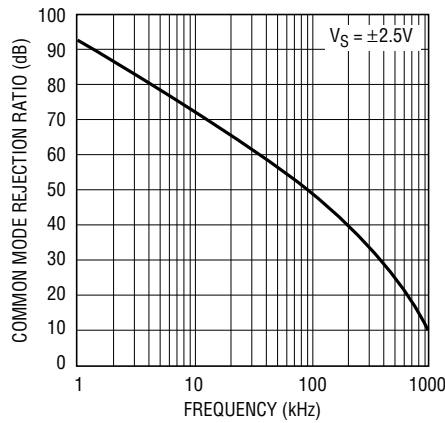
LT1218/19 • TPC13

LT1218 Gain Bandwidth and Phase Margin vs Supply Voltage



LT1218/19 • TPC

LT1218 Common Mode Rejection Ratio vs Frequency



LT1218/19 • TPC15

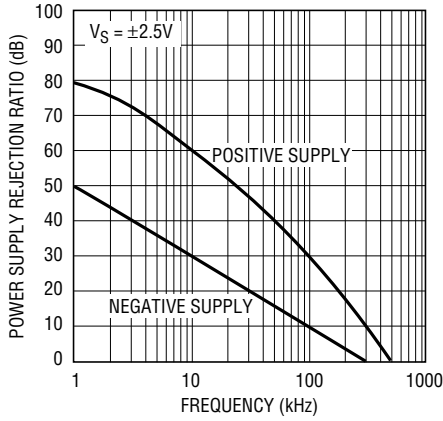
LT1219 Power Supply Rejection Ratio vs Frequency



LT1218/19 • TPC16

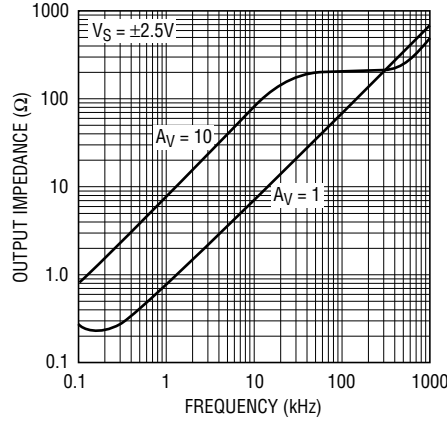
TYPICAL PERFORMANCE CHARACTERISTICS

LT1218 Power Supply Rejection Ratio vs Frequency



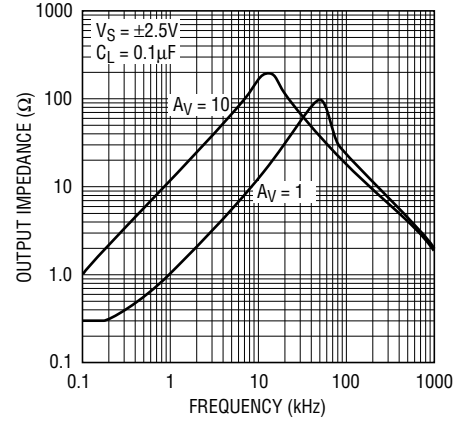
LT1218/19 • TPC17

LT1218 Closed Loop Output Impedance vs Frequency



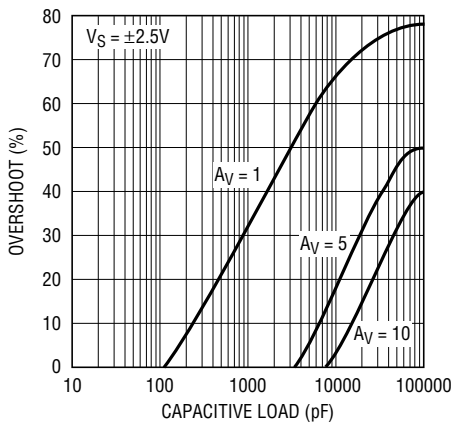
LT1218/19 • TPC18

LT1219 Closed Loop Output Impedance vs Frequency



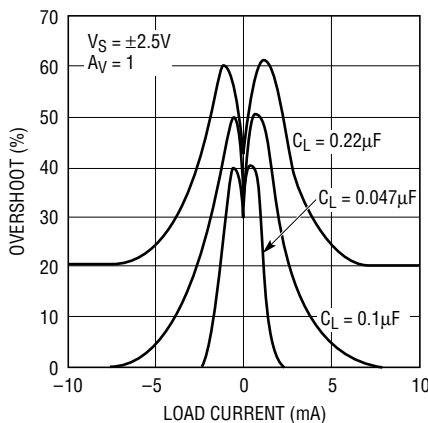
LT1218/19 • TPC19

LT1218 Capacitive Load Handling



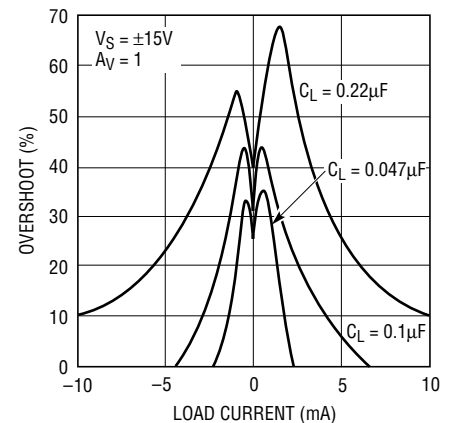
LT1218/19 • TPC20

LT1219 Overshoot vs Load Current, V_S = ±2.5V



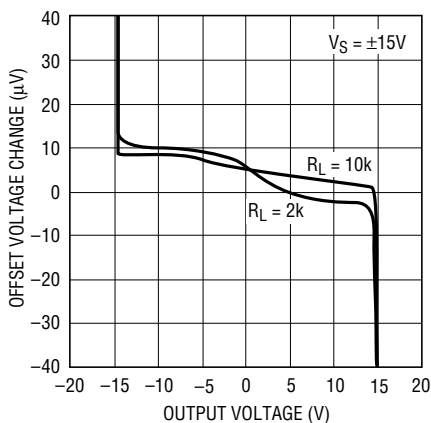
LT1218/19 • TPC21

LT1219 Overshoot vs Load Current, V_S = ±15V



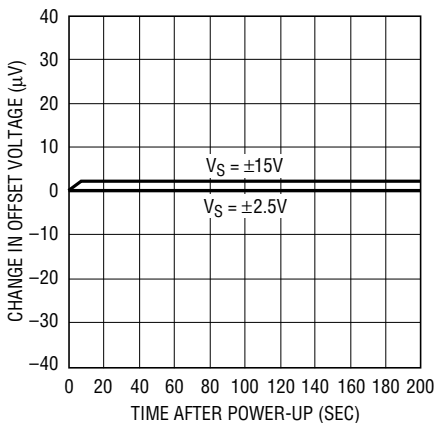
LT1218/19 • TPC22

Open-Loop Gain, V_S = ±15V



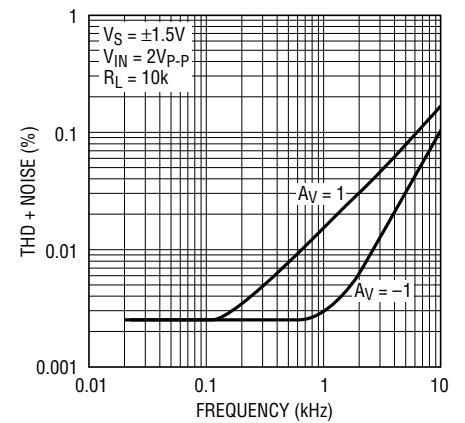
LT1218/19 • TPC23

Input Offset Drift vs Time



LT1218/19 • TPC24

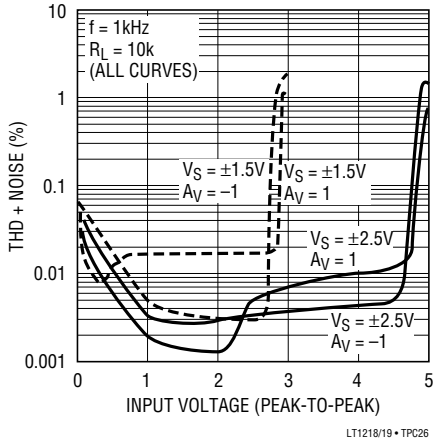
THD + Noise vs Frequency



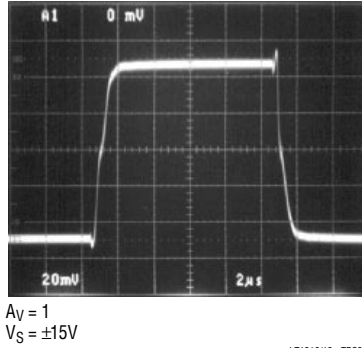
LT1218/19 • TPC25

TYPICAL PERFORMANCE CHARACTERISTICS

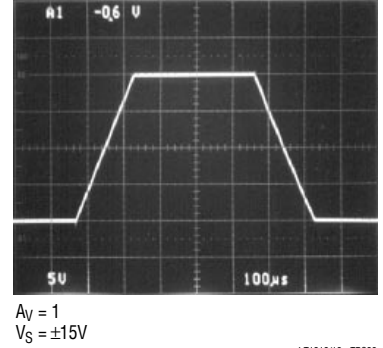
THD + Noise vs Peak-to-Peak Voltage



Small-Signal Response
 $V_S = \pm 15\text{V}$



Large-Signal Response
 $V_S = \pm 15\text{V}$



APPLICATIONS INFORMATION

Rail-to-Rail Operation

The LT1218/LT1219 differ from conventional op amps in the design of both the input and output stages. Figure 1 shows a simplified schematic of the amplifier. The input stage consists of two differential amplifiers, a PNP stage

Q1/Q2 and an NPN stage Q3/Q4, which are active over different portions of the input common mode range. Lateral devices are used in both input stages, eliminating the need for clamps across the input pins. Each input stage is trimmed for offset voltage. A complementary output configuration (Q23 through Q26) is employed to create an



Figure 1. LT1218 Simplified Schematic Diagram

APPLICATIONS INFORMATION

output stage with rail-to-rail swing. The amplifier is fabricated on Linear Technology’s proprietary complementary bipolar process, which ensures very similar DC and AC characteristics for the output devices Q24 and Q26.

A simple comparator Q5 steers current from current source I_1 between the two input stages. When the input common mode voltage V_{CM} is near the negative supply, Q5 is reverse biased, and I_1 becomes the tail current for the PNP differential pair Q1/Q2. At the other extreme, when V_{CM} is within about 1.3V from the positive supply, Q5 diverts I_1 to the current mirror D3/Q6, which furnishes the tail current for the NPN differential pair Q3/Q4.

The collector currents of the two input pairs are combined in the second stage, consisting of Q7 through Q11. Most of the voltage gain in the amplifier is contained in this stage. Differential amplifier Q14/Q15 buffers the output of the second stage, converting the output voltage to differential currents. The differential currents pass through current mirrors D4/Q17 and D5/Q16, and are converted to differential voltages by Q18 and Q19. These voltages are also buffered and applied to the output Darlington pairs Q23/Q24 and Q25/Q26. Capacitors C1 and C2 form local feedback loops around the output devices, lowering the output impedance at high frequencies.

Input Offset Voltage

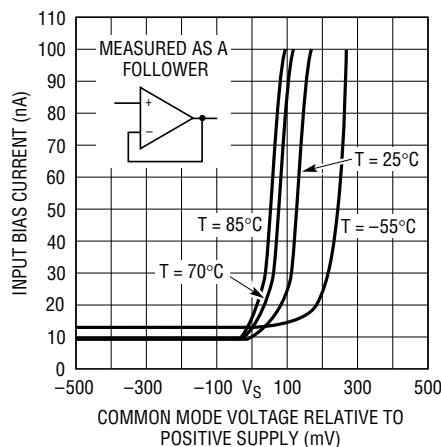
Since the amplifier has two input stages, the input offset voltage changes depending upon which stage is active. The input offsets are random, but bounded voltages. When the amplifier switches between stages, offset voltages may go up, down or remain flat; but will not exceed the guaranteed limits. This behavior is illustrated in three distribution plots of input offset voltage in the Typical Performance Characteristics section.

Overdrive Protection

Two circuits prevent the output from reversing polarity when the input voltage exceeds the common mode range. When the noninverting input exceeds the positive supply by approximately 300mV, the clamp transistor Q12 (Fig-

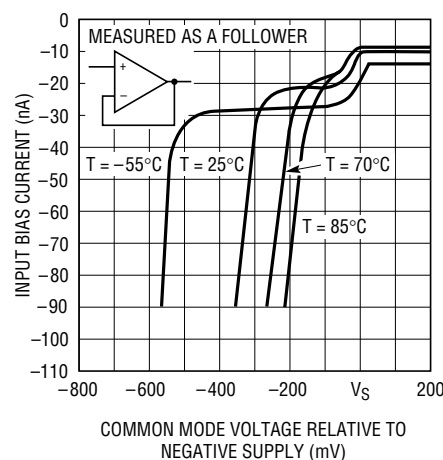
ure 1) turns on, pulling the output of the second stage low, which forces the output high. For input below the negative supply, diodes D1 and D2 turn on, overcoming the saturation of the input pair Q1/Q2.

When overdriven, the amplifier draws input current that exceeds the normal input bias current. Figures 2 and 3 show typical input current as a function of input voltage. The input current must be less than 10mA for the phase reversal protection to work properly. When the amplifier is severely overdriven, an external resistor should be used to limit the overdrive current.



LT1218/19 • F02

Figure 2. Input Bias Current vs Common Mode Voltage



LT1218/19 • F03

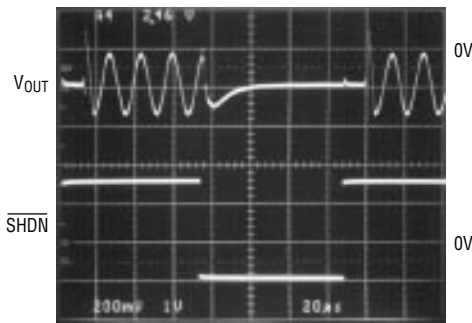
Figure 3. Input Bias Current vs Common Mode Voltage

APPLICATIONS INFORMATION

Shutdown

The biasing of the LT1218/LT1219 is controlled by the $\overline{\text{SHDN}}$ pin. When the $\overline{\text{SHDN}}$ pin is low, the part is shut down. In the shutdown mode, the output looks like a 40pF capacitor and the supply current is less than 30 μA . The $\overline{\text{SHDN}}$ pin is referenced to the positive supply through an internal bias circuit (see Figure 1). The $\overline{\text{SHDN}}$ pin current with the pin low is typically 3 μA .

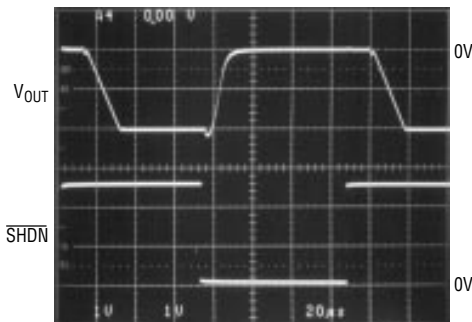
The switching time between the shutdown and active states is about 20 μs , however, the total time to settle will be greater by the slew time of the amplifier. For example, if the DC voltage at the amplifier output is 0V in shutdown and -2V in the active mode, an additional 20 μs is required. Figures 4a and 4b show the switching waveforms for a sinusoidal and a -2V DC input to the LT1218.



$R_L = 10V$
 $V_S = \pm 2.5V$

Figure 4a

LT1218/19 • F04a



$R_L = 10V$
 $V_S = \pm 2.5V$

Figure 4b

LT1218/19 • F04b

The $\overline{\text{SHDN}}$ pin can be driven directly from CMOS logic if the logic and the LT1218/LT1219 are operated from the same supplies. For higher supply operation, an interface is required. An easy way to interface between supplies is to use open-drain logic, an example is shown in Figure 5. Because the $\overline{\text{SHDN}}$ pin is referenced to the positive supply, the logic used should have a breakdown voltage greater than the positive supply.

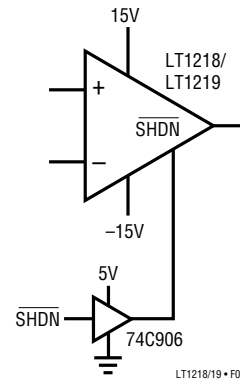


Figure 5. Shutdown Interface

Trim Pins

Trim pins are provided for compatibility with other single op amps. Input offset voltage can be adjusted over a $\pm 2.3\text{mV}$ range with a 10k potentiometer.

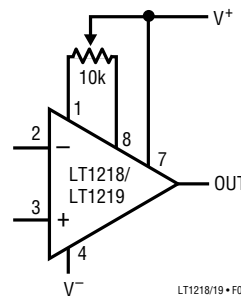


Figure 6. Optional Offset Nulling

Improved Supply Rejection in the LT1219

The LT1219 is a variation of the LT1218 offering greater supply rejection and lower high frequency output impedance. The LT1219 requires a 0.1 μF load capacitance for

APPLICATIONS INFORMATION

compensation. The output capacitance forms a filter, which reduces pickup from the supply and lowers the output impedance. This additional filtering is helpful in mixed analog/digital systems with common supplies or systems employing switching supplies. Filtering also reduces high frequency noise, which may be beneficial when driving A/D converters.

Figures 7a and 7b show the outputs of the LT1218/LT1219 perturbed by a 200mV_{p-p} 50kHz square wave added to the

positive supply. The LT1219 power supply rejection is about ten times greater than that of the LT1218 at 50kHz. Note the 5-to-1 scale change in the output voltage traces.

The tolerance of the external compensation capacitor is not critical. The plots of Overshoot vs Load Current in the Typical Performance Characteristics section illustrate the effect of a capacitive load.



LT1218/19 • F07a

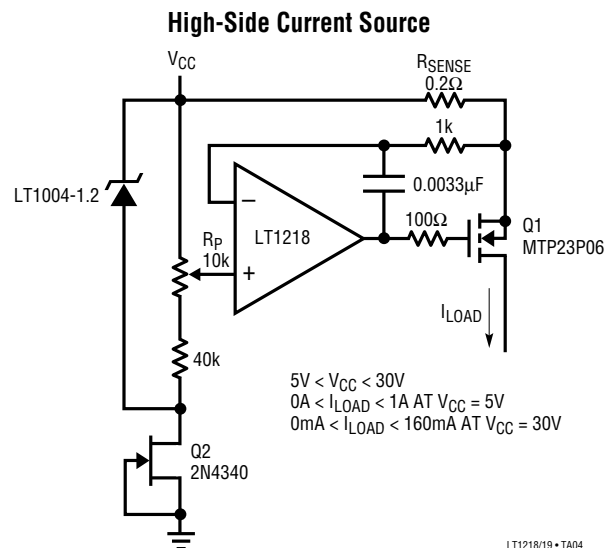
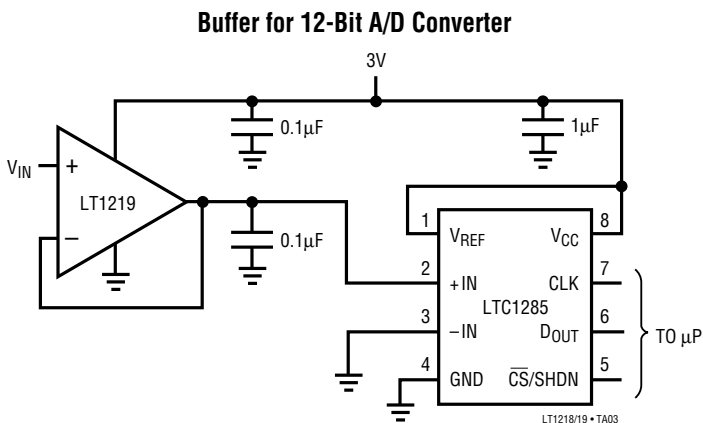
Figure 7a. LT1218 Power Supply Rejection Test



LT1218/19 • F07b

Figure 7b. LT1219 Power Supply Rejection Test

TYPICAL APPLICATIONS



TYPICAL APPLICATIONS

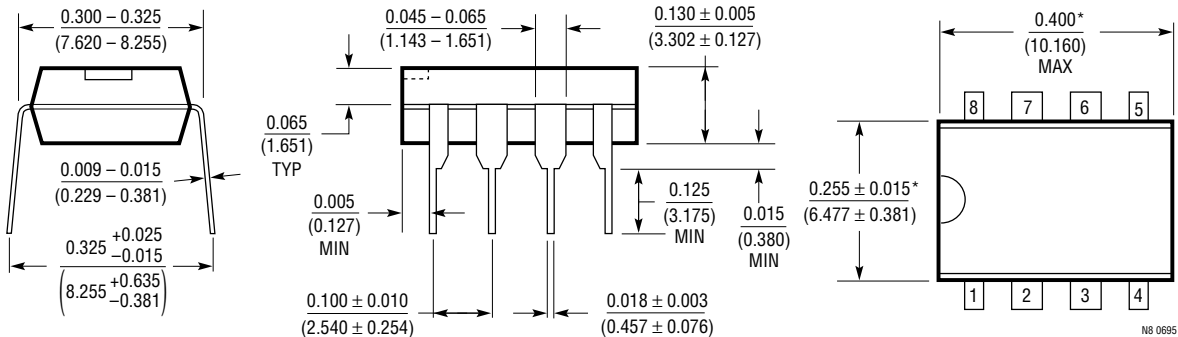
Positive Supply Current Sense



PACKAGE DESCRIPTION

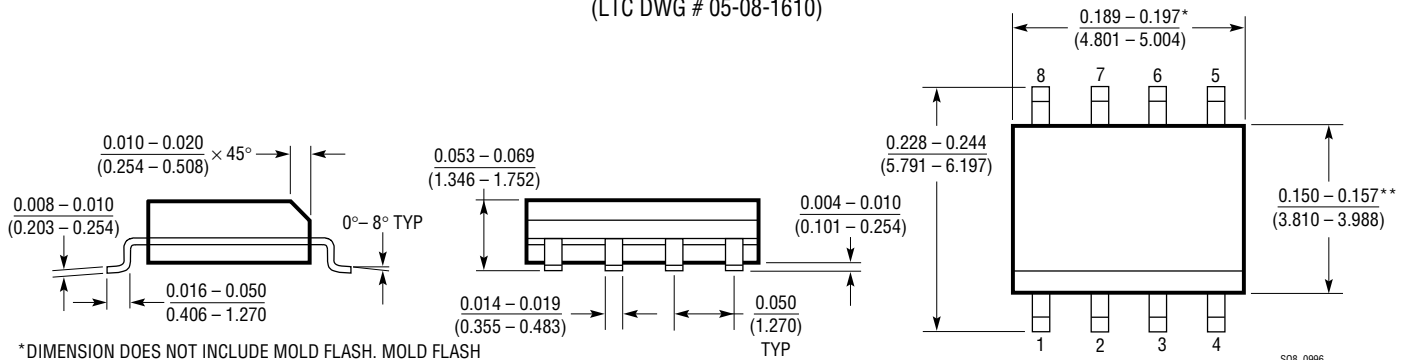
Dimensions in inches (millimeters) unless otherwise noted.

N8 Package 8-Lead PDIP (Narrow 0.300) (LTC DWG # 05-08-1510)



*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.254mm)

S8 Package 8-Lead Plastic Small Outline (Narrow 0.150) (LTC DWG # 05-08-1610)

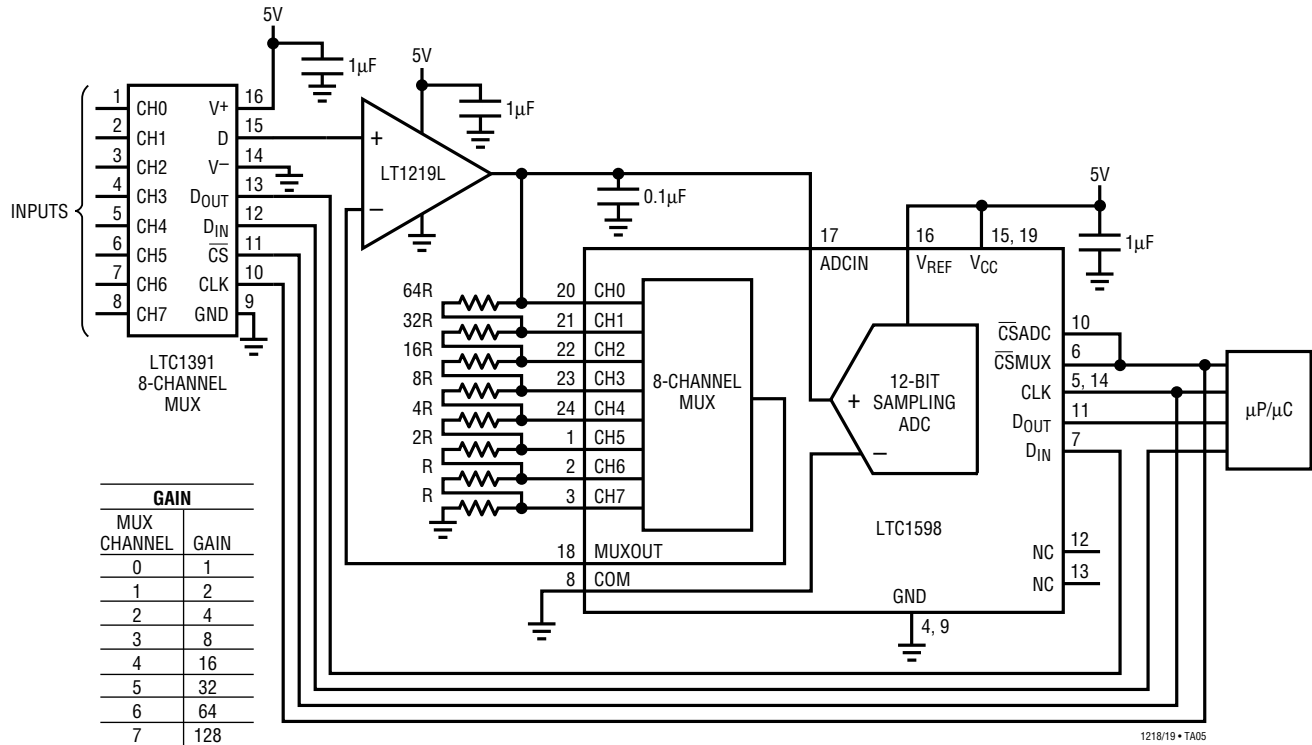


*DIMENSION DOES NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE

**DIMENSION DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE

TYPICAL APPLICATION

8-Channel, 12-Bit Data Acquisition System with Programmable Gain



RELATED PARTS

| PART NUMBER | DESCRIPTION | COMMENTS |
|-----------------------|---|---|
| LTC [®] 1152 | Rail-to-Rail Input and Output, Zero-Drift Op Amp | High DC Accuracy, 10 μ V $V_{OS(MAX)}$, 100nV/ $^{\circ}$ C Drift, 0.7MHz GBW, 0.5V/ μ s Slew Rate, Maximum Supply Current 3mA |
| LT1366/LT1367 | Dual/Quad Precision, Rail-to-Rail Input and Output Op Amps | 475 μ V $V_{OS(MAX)}$, 400kHz GBW, 0.13V/ μ s Slew Rate, Maximum Supply Current 520 μ A per Op Amp |
| LT1466/LT1467 | Dual/Quad Micropower, Rail-to-Rail Input and Output Op Amps | Maximum Supply Current 75 μ A per Op Amp, 390 μ V $V_{OS(MAX)}$, 120kHz Gain Bandwidth |